

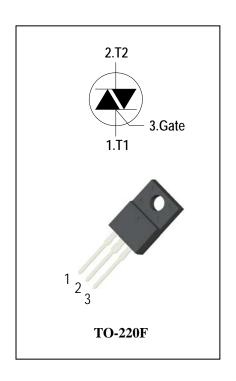
3 Quadrants High temperature Triacs

General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADS16CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance at given junction temperatures.

Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 16 A)
- ♦ High Commutation dv/dt
- High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant
- ◆ Isolation Voltage(V_{ISO}=1500V AC)



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Denetitive Deals Off Chate Valtage	ADS16CH60F		600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS16CH80F	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T _C = 100 °C		16	Α
I _{TSM}	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		160/168	Α
I ² t	I ² t for fusing	tp=10ms		144	A ² s
-11/-14	Critical rate of rise of on-state $F = 120 \text{ Hz Tj} = 150^{\circ}\text{C}$ current $I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$			50	A /
dI/dt			50	A/µs	
I_{GM}	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 150	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C



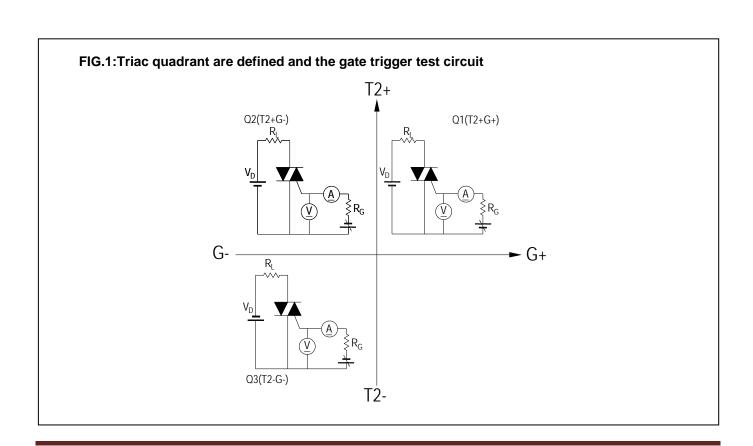




ADS16CH60F/80F

Electrical Characteristics(Tj = 25°C unless otherwise specified)

Symbol	Items		Conditions		ADS16CH60F/80F			Unit
					S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		V _{DRM} = V _{RRM} , Tj = 25°C		5		uA	
I _{RRM}	Current		$V_{DRM} = V_{RRM}$, $Tj = 150$ °C	Max.	6.1		mA	
V_{TM}	Peak On-S	tate Voltage	I _{TM} = 22.5A, t _p = 380 μs	Max.	1.55			V
V_{GD}	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		V	
V_{GT}	Q1-Q2-Q3	Gate Trigger Voltage	1/ 40V D 000	Max.	1.5			V
I _{GT}	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$ Max.		10	35	50	mA
I _H	Q1-Q2-Q3	Holding Current	I _T = 0.1A	Max.	20	45	70	mA
	Q1-Q3	Latabia a Commant	1 - 401	Max.	20	50	90	mA
IL	Q2	Latching Current	$I_G = 1.2 I_{GT}$		35	80	110	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	500	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		$V_D=400V(dI/dt)c=-7A/ms$ $Tj = 150^{\circ}C$	Min.	1	15	20	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	2.1		°C/W		
R _{th(j-a)}	Junction to ambient		Max.	60			°C/W	



ADV

FIG.2: Maximum on-state power dissipation

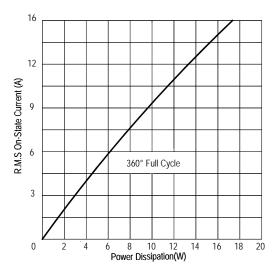


FIG.4: Maximum transient thermal impedance

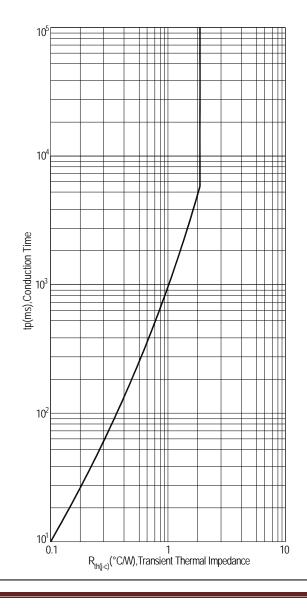


FIG.3: Typical RMS on-state current VS Allowable case Temperature

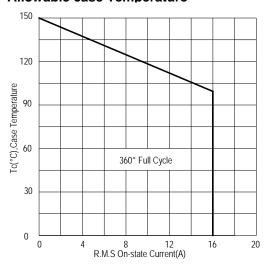


FIG.5: Rated surge on-state current (Non-Repetitive)

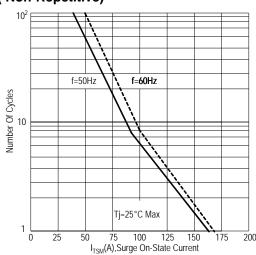
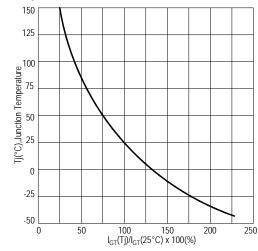


FIG.6: Gate trigger current VS Junction temperature





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FIG.7:Holding current and Latching current VS Junction temperature

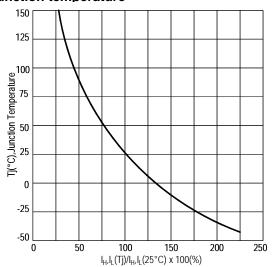


FIG.8: Gate trigger voltage VS Junction temperature

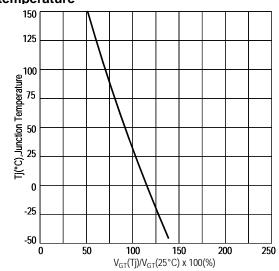
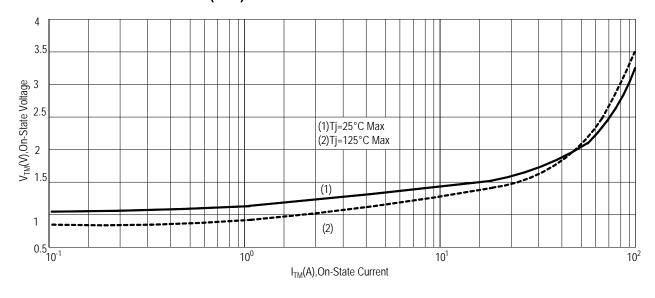


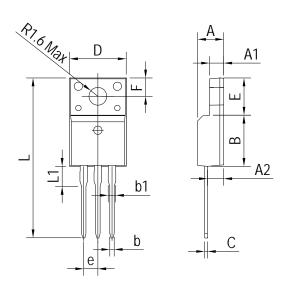
FIG.9: On-state characteristics(Max)



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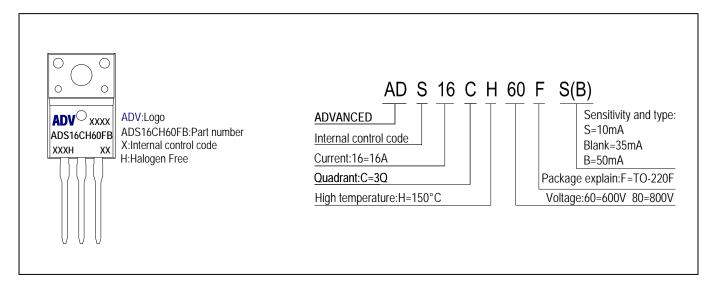


PACKAGE MECHANICAL DATA TO-220F Package Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	4.300	4.800	0.169	0.189	
A1	2.400	2.700	0.094	0.106	
A2	2.500	3.000	0.098	0.118	
В	8.800	9.300	0.346	0.367	
b	0.600	0.950	0.023	0.037	
b1	1.100	1.700	0.043	0.067	
С	0.500	0.750	0.020	0.030	
D	9.700	10.360	0.382	0.408	
Е	6.400	6.800	0.252	0.268	
е	2.540 TYP		0.100 TYP		
F	3.300 REF		0.130 REF		
L	L 28.000 30.000		1.102	1.181	
L1	2.900	3.630	0.114	0.143	

Making Diagram



Ordering information

Part number	Package	Marking Packing		Quantity		
ADS16CH60F#	TO-220F	ADS16CH60F#	Tube	50pcs		
ADS16CH80F#	TO-220F	ADS16CH80F#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



ADS16CH60F/80F

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